

MC3122F • MC3022F MC3122L • MC3022L,P



This device consists of four 2-input Exclusive NOR gates. They can be used to build parity checking/generating functions. Up/down counters can be built using these gates and J-K flip-flops.



Positive Logic: 3 = 1 • 2 + 1 • 2

Input Loading Factor = 1.6 Output Loading Factor = 8 Total Power Dissipation = 85 mW typ/pkg Propagation Delay Time = 14 ns typ

SWITCHING TIME TEST CIRCUIT AND WAVEFORMS



See General Information section for packaging.

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Test procedures are shown for only one gate. The other gate is tested in the same manner. Further, test procedures are shown for only one input of the gate under test. To complete testing, sequence through remaining inputs.



							TES	TEST CURRENT/VOLTAGE VALUES	/VOLTAG	SE VALLIES				
					Γ					1	Valte			
9	@ Test		HI								112			
Ten	Temperature	lor	ној	=	-°	VIL	۷ _{IH}	۷۶	<pre></pre>	V _{RH}	۲ _{cc}	VccL	V _{cc} V _{ccl} V _{cch}	V _{max}
_	(-55°C	16	-1.6			1.1 2.0	2.0	0.4	2.4	4.0	5.0	4.5	5.5	1
MC3122	+25°C	16	-1.6	2.0	-10	-1.6 2.0 -10 1.1 1.8	1.8	0.4	2.4	4.0	5.0	4.5	5.5	7.0
	(+125°C	16	-1.6			0.8 1.8	1.8	0.4	2.4	4.0	5.0	4.5	5.5	
) 0°C	16	-1.6	'	1	1.1 2.0	2.0	0.4	2.5	4.0	5.0	5.0 4.75	5.25	
MC3022	+25°C	16	-1.6	2.0	-10	-1.6 2.0 -10 1.1 1.8	1.8	0.4	2.5	4.0	5.0	5.0 4.75	5.25	7.0
	(+75°C	16	-1.6	•	•	0.9 1.8	1.8	0.4	2.5	4.0	5.0	5.0 4.75	5.25	
Test Limits					E	ST CUR	RENT//	OLTAGE AF	PLIED T	TEST CURRENT/VOLTAGE APPLIED TO PINS LISTED BELOW:	D BELO			

															-	+75°C	16	-1.6	- 9		0.9	9 1.8	8 0.4	2.5	4.0	5.0	4.75	5 5.25	'	1	
		i			MC3122		Test Limits	its				MC3	322 T	MC3022 Test Limits	lits						EST C	URREN	T/VOLTAGE	APPLIED	test current/voltage applied to pins listed below:	D BELC	:MC				
		Under		-55°C	+25°C	5°C	Ŧ	+125°C			0°C	+	+25°C		+75°C			F	F	F	L	+		F		L				Т	
Characteristic	Symbol	Test Min Max Min Max	Min	Max	Min	Max		Min Max	Unit	Min	Max		Max	Min	Min Max Min Max	Unit	lot	но	1 lin	9	Va	× HH	r VF	< K	VRH	Vcc	Vcct	1 VccH	H V _{max}	×	Gnd
Input Forward Current	$\mathbf{I}_{\mathbf{F}}$	1	- 10	-3.0	i zi	-3.0	1	-3.0	-3.0 mAdc	•	-3.0	•	-3.0	-	-3.0	-3.0 mAdc	,	1.		•	- 1.7	1	1	•	2	•		14	'	4,5	4,5,7,9,10,12,13
Leakage Current	IR	I		100	•	100	1	100	μAdc	-	100		100	1	100	μAdc	'	•	1	1	-	•	r	1	,	•	1	14	1	2,4	2,4,5,7,9,10,12,13
Breakdown Voltage	BVin	1	•	1	5.5	•	•		Vdc	•	1	5.5		,	•	Vdc	,	•	1	•		•				'	-	14	•	2,4,	2,4,5,7,9,10,12,13
Clamp Voltage	VD	1	•		1	-1.5	•	•	Vdc	•			-1.5		•	Vdc	,	'	'	-	'	•	1	•	1	1.	14	'	•	4,5	4,5,7,9,10,12,13
Output Output Voltage	VOL			0.4	1.1	0.4		0.4	Vdc	• •	0.4 0.4		0.4		0.4	Vdc		• •		• •	7 2	1 5	·	•••		• •	14	• •	• •	4,4,	4,5,7,9,10,12,13 4,5,7,9,10,12,13
	нол	° °	2.4	1 1	2.4	• •	2.4	• •	Vdc	2.5	11	2.5	11	2.5	• •	Vdc	1.1	~ ~			1,2	1,2	• •		• •	• •	14 14			4,5	4,5,7,9,10,12,13 4,5,7,9,10,12,13
Short-Circuit Current	Isc	3	-20	-65	-20	-65	-20	-65	mAdc	c -20	-65	-20	-65	-20	-65	mAdc	1		!	,	'	•	1,2	•	•	1	•	14	•	3,4	3,4,5,7,9,10,12,13
Power Requirements (Total Device) Maximum Power Supply Current	Imax	14	1.5	in a s	1	24.8		3.1	mAdc	1 1 1		,	24.8	1		mAdc		. •	,	1		,	1,2,4,5,9, 10,12,13	، مُ			1		14	1. A.	7
Power Supply Drain	HOd	14		34.4	17	34.4	1	34.4	mAdc	•	34.4	,	34.4	1	34.4	mAdc		•	1	. 1	'	•	2,5,10,13	3 -	1,4,9,12,	•	1	14	1		7
	Ipdi	14	10	17.8		17.8		17.8	mAdc	1	17.8	1	17.8	•	17.8	mAdc	•	•	•	•	•	•	1,2,4,5,9, 10,12,13	•	•	1	1	14	•		7
Switching Parameters			1. 24		-													1	-		-			_		:					
Turn-Un Delay	-bd-	1,3	,	•		77		,	us		•		22	'	'	us	-	•	'	'	'	'		•		14			-	2,4	2,4,0,1,9,10,12,13
Turn-Off Delay	tpd+	1,3	,		i.	22	1.	,	su	•	1	1	22	1.		su	-	1	'	1	1	1	-			14			'	2,4	2,4,5,7,9,10,12,13

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Plns not listed are left open.